Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** 0.445 inches **Overall Diameter:** 0.255 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.438 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.8 breakdown voltage, dc **Current Rating Per Characteristic:** 1.50 amperes forward current, average peak **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 165.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0